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NOT RECOMMENDED FOR NEW DESIGNS

## Features

- Throughput Rate . . . . . . . . . . . . . . . . . . . . . . 125MSPS
- Low Power . . . . . . . . . . . . . 330mW at 5V, 170 mW at 3 V
- Integral Linearity Error

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\(\pm 0.25\) LSB
```

- Differential Linearity
- Channel Isolation (Typ)
- SFDR to Nyquist at 10 MHz Output . . . . . . . . . . . . 60dBc
- Internal 1.2V Bandgap Voltage Reference
- Single Power Supply from +5 V to +3 V
- CMOS Compatible Inputs
- Excellent Spurious Free Dynamic Range


## Applications

- Direct Digital Frequency Synthesis
- Wireless Communications
- Signal Reconstruction
- Arbitrary Waveform Generators
- Test Equipment
- High Resolution Imaging Systems



## Typical Applications Circuit



NOTE: Recommended separate analog and digital ground planes, connected at a single point near the device. See AN9827.

Functional Block Diagram


## Absolute Maximum Ratings

Digital Supply Voltage DV ${ }_{\text {DD }}$ to DCOM . . . . . . . . . . . . . . . . +5.5 V
Analog Supply Voltage AV ${ }_{\text {DD }}$ to ACOM. . . . . . . . . . . . . . . . . . +5.5 V
Grounds, ACOM TO DCOM . . . . . . . . . . . . . . . . . . . - 0.3 V to +0.3V
Digital Input Voltages (D7-D0, CLK, SLEEP) . . . . . . . DV DD +0.3 V
Internal Reference Output Current. . . . . . . . . . . . . . . . . . . . . $\pm 50 \mu \mathrm{~A}$
Reference Input Voltage Range. . . . . . . . . . . . . . . . . . AV $\mathrm{AD}_{\mathrm{DD}}+0.3 \mathrm{~V}$
Analog Output Current (IOUT) . . . . . . . . . . . . . . . . . . . . . . . . . 24mA

## Operating Conditions

Temperature Range

## ge. .

$\qquad$ $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$

## Thermal Information

| Thermal Resistance (Typical, Note 1) | $\theta_{\mathrm{JA}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| :---: | :---: |
| LQFP Package. | 75 |
| Maximum Junction Temperature | $150^{\circ} \mathrm{C}$ |
| Maximum Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ |
| Maximum Lead Temperature (Sold | $300^{\circ} \mathrm{C}$ |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
NOTE:

1. $\theta_{\mathrm{JA}}$ is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications $\quad A V_{D D}=+5 \mathrm{~V}, D V_{D D}=+5 \mathrm{~V}, \mathrm{~V}_{R E F}=$ Internal $1.2 \mathrm{~V}, I \mathrm{OUTFS}=20 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ for All Typical Values. Data given is per channel except for 'Power Supply Characteristics.'

| PARAMETER | TEST CONDITIONS | $\begin{gathered} \mathrm{HI} 5628 \mathrm{IN} \\ \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { TO } 85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX |  |
| SYSTEM PERFORMANCE (Per Channel) |  |  |  |  |  |
| Resolution |  | 8 | - | - | Bits |
| Integral Linearity Error, INL | "Best Fit" Straight Line (Note 7) | -0.5 | $\pm 0.25$ | +0.5 | LSB |
| Differential Linearity Error, DNL | (Note 7) | -0.5 | $\pm 0.25$ | +0.5 | LSB |
| Offset Error, IOS | (Note 7) | -0.025 | - | +0.025 | \% FSR |
| Offset Drift Coefficient | (Note 7) | - | 0.1 | - | $\begin{gathered} \mathrm{ppm} \\ \mathrm{FSR} /{ }^{\circ} \mathrm{C} \end{gathered}$ |
| Full Scale Gain Error, FSE | With External Reference (Notes 2, 7) | -10 | $\pm 2$ | +10 | \% FSR |
|  | With Internal Reference (Notes 2, 7) | -10 | $\pm 1$ | +10 | \% FSR |
| Full Scale Gain Drifta | With External Reference (Note 7) | - | $\pm 50$ | - | ${\mathrm{FSR} /{ }^{\circ} \mathrm{C} \mathrm{C}}^{\mathrm{pp}}$ |
|  | With Internal Reference (Note 7) | - | $\pm 100$ | - | $\mathrm{FSR} /{ }^{\circ} \mathrm{C}$ |
| Gain Matching Between Channels |  | -0.5 | 0.1 | 0.5 | dB |
| I/Q Channel Isolation | $\mathrm{F}_{\text {OUT }}=10 \mathrm{MHz}$ | - | 80 | - | dB |
| Output Voltage Compliance Range | (Note 3) | -0.3 | - | 1.25 | V |
| Full Scale Output Current, IFS |  | 2 | - | 20 | mA |
| DYNAMIC CHARACTERISTICS (Per Channel) |  |  |  |  |  |
| Clock Rate, fCLK | (Note 3, 9) | 125 | - | - | MHz |
| Output Settling Time, (tsETT) | 0.8\% ( $\pm 1 \mathrm{LSB}$, equivalent to 7 Bits) (Note 7) | - | 5 | - | ns |
|  | 0.4\% ( $\pm 1 / 2 \mathrm{LSB}$, equivalent to 8 Bits) (Note 7) | - | 15 | - | ns |
| Singlet Glitch Area (Peak Glitch) | $\mathrm{R}_{\mathrm{L}}=25 \Omega$ (Note 7) | - | 5 | - | $\mathrm{pV} \cdot \mathrm{s}$ |
| Output Rise Time | Full Scale Step | - | 1.5 | - | ns |
| Output Fall Time | Full Scale Step | - | 1.5 | - | ns |
| Output Capacitance |  | - | 10 | - | pF |
| Output Noise | IOUTFS $=20 \mathrm{~mA}$ | - | 50 | - | $\mathrm{pA} / \sqrt{\mathrm{Hz}}$ |
|  | IOUTFS $=2 \mathrm{~mA}$ | - | 30 | - | $\mathrm{pA} / \sqrt{\mathrm{Hz}}$ |

Electrical Specifications $\quad A V_{D D}=+5 \mathrm{~V}, \mathrm{DV} \mathrm{VD}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{REF}}=$ Internal 1.2 V, IOUTFS $=20 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ for All Typical Values. Data given is per channel except for 'Power Supply Characteristics.' (Continued)

| PARAMETER | TEST CONDITIONS | $\begin{gathered} \mathrm{HI} 5628 \mathrm{IN} \\ \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { TO } 85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX |  |
| AC CHARACTERISTICS - HI5628IN - 125MHz (Per Channel) |  |  |  |  |  |
| Spurious Free Dynamic Range, SFDR Within a Window | $\mathrm{f}_{\text {CLK }}=125 \mathrm{MSPS}, \mathrm{f}_{\text {OUT }}=32.9 \mathrm{MHz}, 10 \mathrm{MHz} \mathrm{Span} \mathrm{(Notes} \mathrm{4}, \mathrm{7)}$ | - | 70 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=100 \mathrm{MSPS}, \mathrm{fOUT}=5.04 \mathrm{MHz}, 4 \mathrm{MHz}$ Span (Notes 4, 7) | - | 73 | - | dBc |
| Total Harmonic Distortion (THD) to Nyquist | $\mathrm{f}_{\text {CLK }}=100 \mathrm{MSPS}, \mathrm{fOUT}=2.00 \mathrm{MHz}($ Notes 4,7$)$ | - | 67 | - | dBc |
| Spurious Free Dynamic Range, SFDR to Nyquist | $\mathrm{f}_{\text {CLK }}=125 \mathrm{MSPS}, \mathrm{f}_{\text {OUT }}=32.9 \mathrm{MHz}, 62.5 \mathrm{MHz}$ Span ( ( otes 4, 7) | - | 51 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=125 \mathrm{MSPS}, \mathrm{fOUT}=10.1 \mathrm{MHz}, 62.5 \mathrm{MHz}$ Span (Notes 4, 7) | - | 61 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=100 \mathrm{MSPS}$, $\mathrm{f}_{\text {OUT }}=40.4 \mathrm{MHz}, 50 \mathrm{MHz} \mathrm{Span}$ (Notes 4, 7) | - | 48 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=100 \mathrm{MSPS}$, fout $=20.2 \mathrm{MHz}, 50 \mathrm{MHz} \mathrm{Span} \mathrm{(Notes} \mathrm{4}, \mathrm{7)}$ | - | 56 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=100 \mathrm{MSPS}, \mathrm{fout}^{\text {a }}$ 5.04MHz, 50 MHz Span (Notes 4, 7) | - | 68 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=100 \mathrm{MSPS}$, fout $=2.51 \mathrm{MHz}, 50 \mathrm{MHz}$ Span (Notes 4, 7) | - | 68 | - | dBc |
| AC CHARACTERISTICS - HI5628/6IN - 60MHz (Per Channel) |  |  |  |  |  |
| Spurious Free Dynamic Range, SFDR Within a Window | $\mathrm{f}_{\text {CLK }}=60 \mathrm{MSPS}$, fout $=10.1 \mathrm{MHz}, 10 \mathrm{MHz}$ Span (Notes 4, 7) | - | 70 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}$, fout $=5.02 \mathrm{MHz}, 2 \mathrm{MHz} \mathrm{Span}$ (Notes 4, 7) | - | 73 | - | dBc |
|  | $\mathrm{f}_{\mathrm{CLK}}=50 \mathrm{MSPS}, \mathrm{fOUT}=1.00 \mathrm{MHz}, 2 \mathrm{MHz} \mathrm{Span}($ Notes 4, 7 ) | - | 74 | - | dBc |
| Total Harmonic Distortion (THD) to Nyquist | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}, \mathrm{fOUT}=2.00 \mathrm{MHz}($ Notes 4, 7) | - | 67 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}, \mathrm{fOUT}=1.00 \mathrm{MHz}($ Notes 4, 7) | - | 68 | - | dBc |
| Spurious Free Dynamic Range, SFDR to Nyquist | $\mathrm{f}_{\text {CLK }}=60 \mathrm{MSPS}, \mathrm{f}$ OUT $=20.2 \mathrm{MHz}, 30 \mathrm{MHz}$ Span (Notes 4, 7) | - | 54 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=60 \mathrm{MSPS}, \mathrm{f}_{\text {OUT }}=10.1 \mathrm{MHz}, 30 \mathrm{MHz}$ Span (Notes 4, 7) | - | 60 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}, \mathrm{f}$ OUT $=20.2 \mathrm{MHz}, 25 \mathrm{MHz}$ Span (Notes 4, 7) | - | 53 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}, \mathrm{fOUT}=5.02 \mathrm{MHz}, 25 \mathrm{MHz}$ Span (Notes 4, 7) | - | 67 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}, \mathrm{f}$ OUT $=2.51 \mathrm{MHz}, 25 \mathrm{MHz}$ Span (Notes 4, 7) | - | 68 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=50 \mathrm{MSPS}, \mathrm{f}$ OUT $=1.00 \mathrm{MHz}, 25 \mathrm{MHz}$ Span (Notes 4, 7) | - | 68 | - | dBc |
|  | $\mathrm{f}_{\text {CLK }}=25 \mathrm{MSPS}, \mathrm{fOUT}=5.02 \mathrm{MHz}, 25 \mathrm{MHz}$ Span (Notes 4, 7) | - | 71 | - | dBc |
| VOLTAGE REFERENCE |  |  |  |  |  |
| Internal Reference Voltage, $\mathrm{V}_{\text {FSADJ }}$ | Voltage at Pin 22 with Internal Reference | 1.04 | 1.16 | 1.28 | V |
| Internal Reference Voltage Drift |  | - | $\pm 60$ | - | ppm/ $/{ }^{\circ} \mathrm{C}$ |
| Internal Reference Output Current Sink/Source Capability |  | - | 0.1 | - | $\mu \mathrm{A}$ |
| Reference Input Impedance |  | - | 1 | - | $\mathrm{M} \Omega$ |
| Reference Input Multiplying Bandwidth | (Note 7) | - | 1.4 | - | MHz |
| DIGITAL INPUTS D7-D0, CLK (Per Channel) |  |  |  |  |  |
| Input Logic High Voltage with 5 V Supply, $\mathrm{V}_{\mathrm{IH}}$ | (Note 3) | 3.5 | 5 | - | V |
| Input Logic High Voltage with 3V Supply, VIH | (Note 3) | 2.1 | 3 | - | V |
| Input Logic Low Voltage with 5 V Supply, VIL | (Note 3) | - | 0 | 1.3 | V |
| Input Logic Low Voltage with 3V Supply, VIL | (Note 3) | - | 0 | 0.9 | V |
| Input Logic Current, $\mathrm{I}_{\mathrm{IH}}$ |  | -10 | - | +10 | $\mu \mathrm{A}$ |
| Input Logic Current, $\mathrm{I}_{\text {IL }}$ |  | -10 | - | +10 | $\mu \mathrm{A}$ |
| Digital Input Capacitance, $\mathrm{C}_{\text {IN }}$ |  | - | 5 | - | pF |
| TIMING CHARACTERISTICS (Per Channel) |  |  |  |  |  |

Electrical Specifications $\quad A V_{D D}=+5 \mathrm{~V}, \mathrm{DV} \mathrm{VD}=+5 \mathrm{~V}, \mathrm{~V}_{\mathrm{REF}}=$ Internal 1.2 V, IOUTFS $=20 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ for All Typical Values. Data given is per channel except for 'Power Supply Characteristics.' (Continued)

| PARAMETER | TEST CONDITIONS | $\begin{gathered} \text { HI5628IN } \\ \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { TO } 85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | MIN | TYP | MAX |  |
| Data Setup Time, ${ }_{\text {ISU }}$ | See Figure 3 (Note 3) | 3 | - | - | ns |
| Data Hold Time, $\mathrm{t}_{\text {HLD }}$ | See Figure 3 (Note 3) | 3 | - | - | ns |
| Propagation Delay Time, tpd | See Figure 3 | - | 1 | - | ns |
| CLK Pulse Width, tPW1, tPW2 | See Figure 3 (Note 3) | 4 | - | - | ns |
| POWER SUPPLY CHARACTERISTICS |  |  |  |  |  |
| $\mathrm{AV}_{\text {DD }}$ Power Supply | (Note 8, 9) | 2.7 | 5.0 | 5.5 | V |
| DV ${ }_{\text {DD }}$ Power Supply | (Note 8, 9) | 2.7 | 5.0 | 5.5 | V |
| Analog Supply Current (IAVDD) | 5 V or 3 V , IOUTFS $=20 \mathrm{~mA}$ | - | 46 | 60 | mA |
|  | 5 V or 3 V , IOUTFS $=2 \mathrm{~mA}$ | - | 8 | - | mA |
| Digital Supply Current (ldvdD) | 5 V , IOUTFS = Don't Care (Note 5) | - | 6 | 10 | mA |
|  | 3V, IOUTFS = Don't Care (Note 5) | - | 3 | - | mA |
| Supply Current (lavDD) Sleep Mode | 5 V or 3V, IOUTFS = Don't Care) | - | 3.2 | 6 | mA |
| Power Dissipation (Both Channels) | 5 V , IOUTFS $=20 \mathrm{~mA}$ (Note 6) | - | 330 | - | mW |
|  | 5 V , IOUTFS $=2 \mathrm{~mA}$ (Notes 6) | - | 140 | - | mW |
|  | 3 V , IOUTFS $=20 \mathrm{~mA}$ (Note 6) | - | 170 | - | mW |
|  | 3 V , IOUTFS $=2 \mathrm{~mA} \mathrm{(Note} \mathrm{6)}$ | - | 54 | - | mW |
|  | 5 V , IOUTFS $=20 \mathrm{~mA}$ (Note 10) | - | 300 | - | mW |
|  | 3.3 V, IOUTFS $=20 \mathrm{~mA}$ (Note 10) | - | 150 | - | mW |
|  | 3 V , IOUTFS $=20 \mathrm{~mA}$ (Note 10) | - | 135 | - | mW |
| Power Supply Rejection | Single Supply (Note 7) | -0.2 | - | +0.2 | $\begin{gathered} \% \\ \text { FSR/V } \end{gathered}$ |

## NOTES:

2. Gain Error measured as the error in the ratio between the full scale output current and the current through $R_{\text {SET }}$ (typically $625 \mu \mathrm{~A}$ ). Ideally the ratio should be 32.
3. Parameter guaranteed by design or characterization and not production tested.
4. Spectral measurements made with differential transformer coupled output and no filtering.
5. Measured with the clock at 50MSPS and the output frequency at 1 MHz , both channels.
6. Measured with the clock at 100MSPS and the output frequency at 40 MHz , both channels.
7. See 'Definition of Specifications'.
8. For operation below 3 V , it is recommended that the output current be reduced to 12 mA or less to maintain optimum performance. $\mathrm{DV}_{\mathrm{DD}}$ and $A V_{D D}$ do not have to be equal.
9. For operation above 125 MHz , it is recommended that the power supply be 3.3 V or greater. The part is functional with the clock above 125MSPS and the power supply below 3.3 V , but performance is degraded.
10. Measured with the clock at 60MSPS and the output frequency at 10 MHz , both channels.

## Timing Diagrams



FIGURE 1. OUTPUT SETTLING TIME DIAGRAM


FIGURE 2. PEAK GLITCH AREA (SINGLET) MEASUREMENT METHOD


FIGURE 3. PROPAGATION DELAY, SETUP TIME, HOLD TIME AND MINIMUM PULSE WIDTH DIAGRAM

## Definition of Specifications

Integral Linearity Error, INL, is the measure of the worst case point that deviates from a best fit straight line of data values along the transfer curve.

Differential Linearity Error, DNL, is the measure of the step size output deviation from code to code. Ideally the step size should be 1 LSB. A DNL specification of 1 LSB or less guarantees monotonicity.

Output Settling Time, is the time required for the output voltage to settle to within a specified error band measured from the beginning of the output transition. The measurement was done by switching from code 0 to 64, or quarter scale. Termination impedance was $25 \Omega$ due to the parallel resistance of the output $50 \Omega$ and the oscilloscope's $50 \Omega$ input. This also aids the ability to resolve the specified error band without overdriving the oscilloscope.

Singlet Glitch Area, is the switching transient appearing on the output during a code transition. It is measured as the area under the overshoot portion of the curve and is expressed as a Volt-Time specification.

Full Scale Gain Error, is the error from an ideal ratio of 32 between the output current and the full scale adjust current (through $\mathrm{R}_{\mathrm{SET}}$ ).

Full Scale Gain Drift, is measured by setting the data inputs to all ones and measuring the output voltage through a known resistance as the temperature is varied from $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$. It is defined as the maximum deviation from the value measured at room temperature to the value measured at either $\mathrm{T}_{\text {MIN }}$ or $\mathrm{T}_{\text {MAX }}$. The units are ppm of FSR (Full Scale Range) per degree C.

Total Harmonic Distortion, THD, is the ratio of the DAC output fundamental to the RMS sum of the first five harmonics.

Spurious Free Dynamic Range, SFDR, is the amplitude difference from the fundamental to the largest harmonically or non-harmonically related spur within the specified window.

Output Voltage Compliance Range, is the voltage limit imposed on the output. The output impedance load should be chosen such that the voltage developed does not violate the compliance range.

Offset Error, is measured by setting the data inputs to all zeros and measuring the output voltage through a known resistance. Offset error is defined as the maximum deviation of the output current from a value of 0 mA .

Offset Drift, is measured by setting the data inputs to all zeros and measuring the output voltage through a known resistance as the temperature is varied from $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$. It is defined as the maximum deviation from the value measured at room temperature to the value measured at
either $\mathrm{T}_{\text {MIN }}$ or $\mathrm{T}_{\text {MAX }}$. The units are ppm of FSR (Full Scale Range) per degree C .

Power Supply Rejection, is measured using a single power supply. Its nominal +5 V is varied $\pm 10 \%$ and the change in the DAC full scale output is noted.

Reference Input Multiplying Bandwidth, is defined as the 3 dB bandwidth of the voltage reference input. It is measured by using a sinusoidal waveform as the external reference with the digital inputs set to all 1 s . The frequency is increased until the amplitude of the output waveform is 0.707 of its original value.

Internal Reference VoItage Drift, is defined as the maximum deviation from the value measured at room temperature to the value measured at either $\mathrm{T}_{\text {MIN }}$ or $\mathrm{T}_{\text {MAX }}$. The units are ppm per degree $C$.

## Detailed Description

The HI5628 is a dual, 8 -bit, current out, CMOS, digital to analog converter. Its maximum update rate is 125MSPS and can be powered by either single or dual power supplies in the recommended range of +3 V to +5 V . It consumes less than 330 mW of power when using a +5 V supply with the data switching at 100MSPS. The architecture is based on a segmented current source arrangement that reduces glitch by reducing the amount of current switching at any one time. The five MSBs are represented by 31 major current sources of equivalent current. The three LSBs are comprised of binary weighted current sources. Consider an input pattern to the converter which ramps through all the codes from 0 to 255. The three LSB current sources would begin to count up. When they reached the all high state (decimal value of 7 ) and needed to count to the next code, they would all turn off and the first major current source would turn on. To continue counting upward, the 3 LSBs would count up another 7 codes, and then the next major current source would turn on and the three LSBs would all turn off. The process of the single, equivalent, major current source turning on and the three LSBs turning off each time the converter reaches another 7 codes greatly reduces the glitch at any one switching point. In previous architectures that contained all binary weighted current sources or a binary weighted resistor ladder, the converter might have a substantially larger amount of current turning on and off at certain, worstcase transition points such as midscale and quarter scale transitions. By greatly reducing the amount of current switching at certain 'major' transitions, the overall glitch of the converter is dramatically reduced, improving settling times and transient problems.

## Digital Inputs and Termination

The HI5628 digital inputs are guaranteed to CMOS levels. However, TTL compatibility can be achieved by lowering the supply voltage to 3 V due to the digital threshold of the input buffer being approximately half of the supply voltage. The internal register is updated on the rising edge of the clock. To minimize reflections, proper termination should be implemented. If the lines driving the clock and the digital inputs are $50 \Omega$ lines, then $50 \Omega$ termination resistors should be placed as close to the converter inputs as possible, connected to the digital ground plane (if separate grounds are used).

## Ground Plane(s)

If separate digital and analog ground planes are used, then all of the digital functions of the device and their corresponding components should be over the digital ground plane and terminated to the digital ground plane. The same is true for the analog components and the analog ground plane. The converter will function properly with a single ground plane, as the Evaluation Board is configured in this matter.

## Noise Reduction

To minimize power supply noise, $0.1 \mu \mathrm{~F}$ capacitors should be placed as close as possible to the converter's power supply pins, $A V_{D D}$ and $D V_{D D}$. Also, should the layout be designed using separate digital and analog ground planes, these capacitors should be terminated to the digital ground for $D V_{D D}$ and to the analog ground for $A V_{D D}$. Additional filtering of the power supplies on the board is recommended.

## Voltage Reference

The internal voltage reference of the device has a nominal value of +1.2 V with a $\pm 60 \mathrm{ppm} /{ }^{\circ} \mathrm{C}$ drift coefficient over the full temperature range of the converter. It is recommended that a $0.1 \mu \mathrm{~F}$ capacitor be placed as close as possible to the REFIO pin, connected to the analog ground. The REFLO pin (15) selects the reference. The internal reference can be selected if pin 15 is tied low (ground). If an external reference is desired, then pin 15 should be tied high (to the analog supply voltage) and the external reference driven into REFIO, pin 23. The full scale output current of the converter is a function of the voltage reference used and the value of RSET. IOUT should be within the 2 mA to 20 mA range, through operation below 2 mA is possible, with performance degradation.

If the internal reference is used, $\mathrm{V}_{\text {FSADJ }}$ will equal approximately 1.16 V (pin 22). If an external reference is used, $\mathrm{V}_{\text {FSADJ }}$ will equal the external reference. The calculation for IOUT (Full Scale) is:

IOUT $($ Full Scale $)=\left(V_{\text {FSADJ }} / R_{\text {SET }}\right) \times 32$.
If the full scale output current is set to 20 mA by using the internal voltage reference $(1.16 \mathrm{~V})$ and a $1.86 \mathrm{k} \Omega \mathrm{R}_{\mathrm{SET}}$ resistor, then the input coding to output current will resemble the following:

TABLE 1. INPUT CODING vs OUTPUT CURRENT

| INPUT CODE (D7-D0) | IOUTA (mA) | IOUTB (mA) |
| :---: | :---: | :---: |
| 11111111 | 20 | 0 |
| 10000000 | 10 | 10 |
| 00000000 | 0 | 20 |

## Outputs

IOUTA and IOUTB (or QOUTA and QOUTB) are complementary current outputs. The sum of the two currents is always equal to the full scale output current minus one LSB. If single ended use is desired, a load resistor can be used to convert the output current to a voltage. It is recommended that the unused output be either grounded or equally terminated. The voltage developed at the output must not violate the output voltage compliance range of -0.3 V to 1.25 V . R LOAD should be chosen so that the desired output voltage is produced in conjunction with the output full scale current, which is described above in the 'Reference' section. If a known line impedance is to be driven, then the output load resistor should be chosen to match this impedance. The output voltage equation is:
$\mathrm{V}_{\text {OUT }}=I_{\text {OUT }} \times R_{\text {LOAD }}$.
These outputs can be used in a differential-to-single-ended arrangement to achieve better harmonic rejection. The SFDR measurements in this data sheet were performed with a 1:1 transformer on the output of the DAC (see Figure 1). With the center tap grounded, the output swing of pins 16 and 17 will be biased at zero volts. It is important to note here that the negative voltage output compliance range limit is -300 mV , imposing a maximum of $600 \mathrm{mV} \mathrm{V}_{\mathrm{P}-\mathrm{P}}$ amplitude with this configuration. The loading as shown in Figure 1 will result in a 500 mV signal at the output of the transformer if the full scale output current of the DAC is set to 20 mA .


FIGURE 4.
$V_{\text {OUT }}=2 \times$ IOUT $\times R_{E Q}$, where $R_{E Q}$ is $\sim 12.5 \Omega$.
Allowing the center tap to float will result in identical transformer output, however the output pins of the DAC will have positive DC offset. The $50 \Omega$ load on the output of the transformer represents the spectrum analyzer's input impedance.

## Pin Descriptions

| PIN NO. | PIN NAME | PIN DESCRIPTION |
| :---: | :---: | :---: |
| 39-32 | QD7 (MSB) Through QD0 (LSB) | Digital Data Bit 7, the Most Significant Bit through Digital Data Bit 0 , the Least Significant Bit, of the Q channel. |
| 1-5, 48-46 | ID7 (MSB) Through ID0 (LSB) | Digital Data Bit 7, the Most Significant Bit through Digital Data Bit 0, the Least Significant Bit, of the I channel. |
| 8 | SLEEP | Control Pin for Power-Down Mode. Sleep Mode is active high; connect to ground for Normal Mode. Sleep pin has internal $20 \mu \mathrm{~A}$ active pulldown current. |
| 15 | REFLO | Connect to analog ground to enable internal 1.2 V reference or connect to $\mathrm{AV}_{\text {DD }}$ to disable. |
| 23 | REFIO | Reference voltage input if internal reference is disabled and reference voltage output if internal reference is enabled. Use $0.1 \mu \mathrm{~F}$ cap to ground when internal reference is enabled. |
| 22 | FSADJ | Full Scale Current Adjust. Use a resistor to ground to adjust full scale output current. Full Scale Output Current Per Channel $=32 \times \mathrm{I}_{\text {FSADJ }}$. |
| 14, 24 | ICOMP1, QCOMP1 | Reduces noise. Connect each to $\mathrm{AV}_{\text {DD }}$ with $0.1 \mu \mathrm{~F}$ capacitor. The ICOMP1 and QCOMP1 pins MUST be tied together externally. |
| 13, 18, 19, 25 | AGND | Analog Ground Connections. |
| 17 | IOUTB | The complementary current output of the I channel. Bits set to all 0 s gives full scale current. |
| 16 | IOUTA | Current output of the I channel. Bits set to all 1 s gives full scale current. |
| 20 | QOUTB | The complementary current output of the Q channel. Bits set to all 0 s gives full scale current. |
| 21 | QOUTA | Current output of the Q channel. Bits set to all 1s gives full scale current. |
| 11, 27 | NC | No Connect. Recommended: Connect to ground. |
| 12, 26 | $A V_{\text {DD }}$ | Analog Supply (+2.7V to +5.5V). |
| $\begin{gathered} 6,7,10,28,30 \\ 31,41,44 \end{gathered}$ | DGND | Digital Ground. |
| 9, 29, 40, 45 | DV ${ }_{\text {DD }}$ | Supply voltage for digital circuitry (+2.7V to +5.5 V ). |
| 43 | ICLK | Clock input for I channel. Positive edge of clock latches data. |
| 42 | QCLK | Clock input for Q channel. Positive edge of clock latches data. |

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